

RB520CS30L

100 mA low V_F MEGA Schottky barrier rectifier Rev. 1 — 10 March 2011

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882 leadless ultra small Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

Average forward current: I_{F(AV)} ≤ 100 mA

Reverse voltage: V_R ≤ 30 V

Low forward voltage: V_F ≤ 450 mV

■ Low reverse current: $I_R \le 0.5 \mu A$

AEC-Q101 qualified

Leadless ultra small SMD plastic package

1.3 Applications

- Low current rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$I_{F(AV)}$	average forward current	square wave; δ = 0.5; f = 20 kHz				
		T _{amb} ≤ 135 °C	<u>[1]</u> _	-	100	mA
		T _{sp} ≤ 145 °C	-	-	100	mA
I _R	reverse current	V _R = 10 V	-	0.14	0.5	μΑ
V_R	reverse voltage		-	-	30	V
V _F	forward voltage	I _F = 10 mA	[2] _	330	450	mV

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm².



^[2] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	. 54
2	anode	1 2	1 2 sym001
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package		
	Name	Description	Version	
RB520CS30L	-	leadless ultra small plastic package; 2 terminals; body 1.0 \times 0.6 \times 0.5 mm	SOD882	

4. Marking

Table 4. Marking codes

Type number	Marking code
RB520CS30L	AP

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	30	V
I _{F(AV)}	average forward current	square wave; δ = 0.5; f = 20 kHz			
		T _{amb} ≤ 135 °C	<u>[1]</u> -	100	mA
		T _{sp} ≤ 145 °C	-	100	mA
I _{FSM}	non-repetitive peak forward current	$\begin{array}{l} \text{half sine wave;} \\ t_p \leq 8.3 \text{ ms} \end{array}$	[2] -	3	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[4][3]	315	mW
			[4][1]	565	mW
			[4][5]	865	mW

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Table 5. Limiting values ... continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [2] $T_i = 25$ °C prior to surge.
- 3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Reflow soldering is the only recommended soldering method.
- [5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

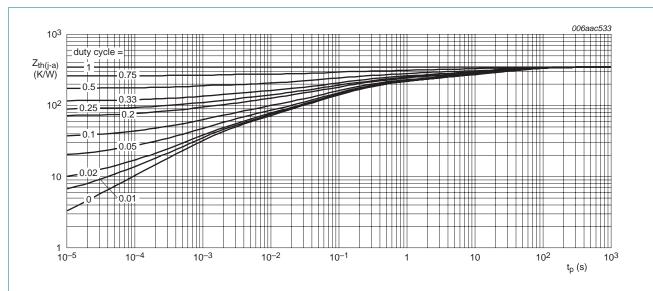
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1][2]				
	junction to ambient		[3]	-	-	395	K/W
			<u>[4]</u>	-	-	220	K/W
			<u>[5]</u>	-	-	145	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		<u>[6]</u>	-	-	70	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [5] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- 6] Soldering point of cathode tab.

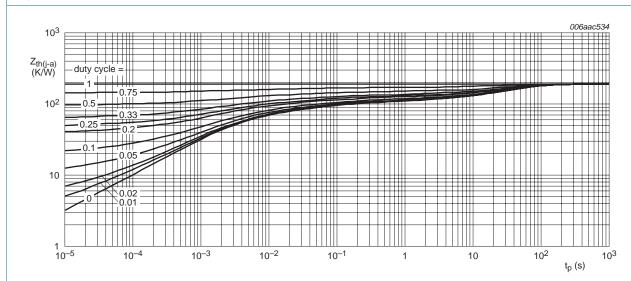
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FR4 PCB, standard footprint

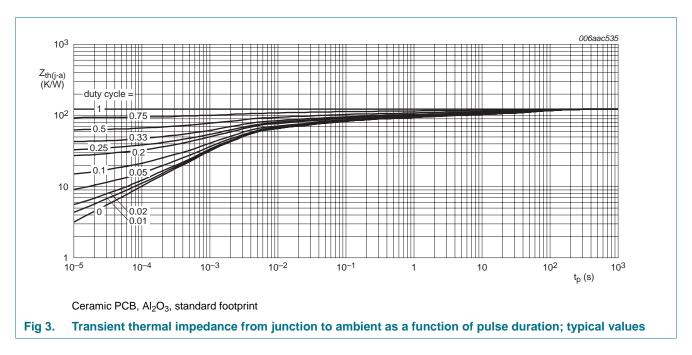
Fig 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for cathode 1 cm²

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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7. Characteristics

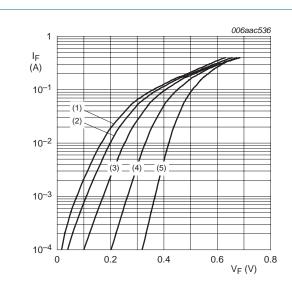
Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	210	-	mV
		I _F = 1 mA	-	270	-	mV
		I _F = 10 mA	-	330	450	mV
		$I_F = 100 \text{ mA}$	-	450	-	mV
I _R	reverse current	V _R = 10 V	-	0.14	0.5	μΑ
C_d	diode capacitance	$V_R = 1 V$; $f = 1 MHz$	-	10	-	pF

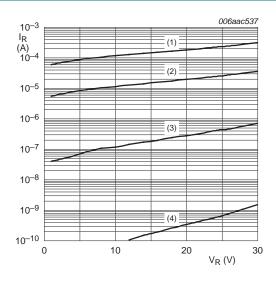
^[1] Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

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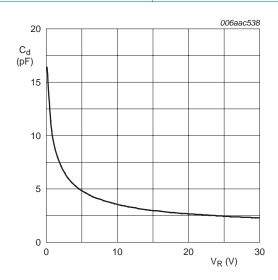
- (1) $T_i = 150 \,^{\circ}\text{C}$
- (2) $T_i = 125 \, ^{\circ}\text{C}$
- (3) $T_i = 85 \, ^{\circ}\text{C}$
- (4) $T_j = 25 \,{}^{\circ}\text{C}$
- (5) $T_i = -40 \, ^{\circ}C$

Fig 4. Forward current as a function of forward voltage; typical values



- (1) $T_j = 125 \, ^{\circ}C$
- (2) $T_j = 85 \, ^{\circ}C$
- (3) $T_j = 25 \, ^{\circ}C$
- (4) $T_j = -40 \, ^{\circ}C$

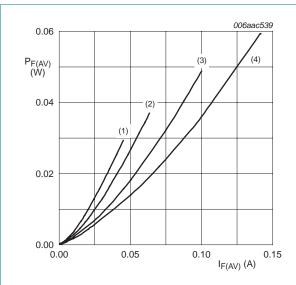
Fig 5. Reverse current as a function of reverse voltage; typical values



f = 1 MHz; T_{amb} = 25 °C

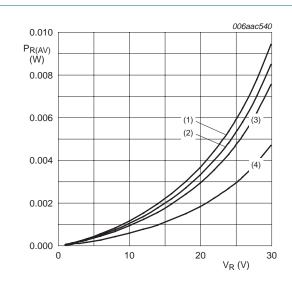
Fig 6. Diode capacitance as a function of reverse voltage; typical values

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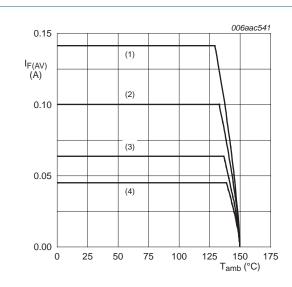
- (1) $\delta = 0.1$
- (2) $\delta = 0.2$
- (3) $\delta = 0.5$
- (4) $\delta = 1$

Fig 7. Average forward power dissipation as a function of average forward current; typical values



- (1) $\delta = 1$; DC
- (2) $\delta = 0.9$; f = 20 kHz
- (3) $\delta = 0.8$; f = 20 kHz
- (4) $\delta = 0.5$; f = 20 kHz

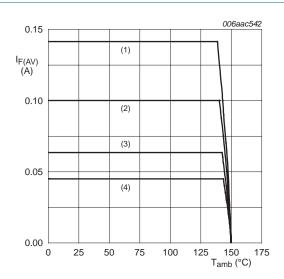
Fig 8. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 9. Average forward current as a function of ambient temperature; typical values

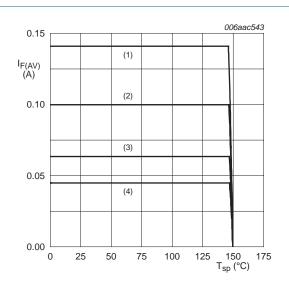


FR4 PCB, mounting pad for cathode 1 cm²

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 10. Average forward current as a function of ambient temperature; typical values

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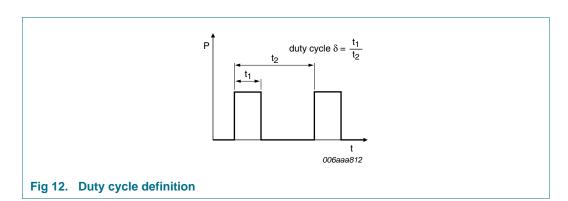


T_i = 150 °C

- (1) $\delta = 1$; DC
- (2) $\delta = 0.5$; f = 20 kHz
- (3) $\delta = 0.2$; f = 20 kHz
- (4) $\delta = 0.1$; f = 20 kHz

Fig 11. Average forward current as a function of solder point temperature; typical values

8. Test information



The current ratings for the typical waveforms as shown in Figure 9, 10 and 11 are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current,

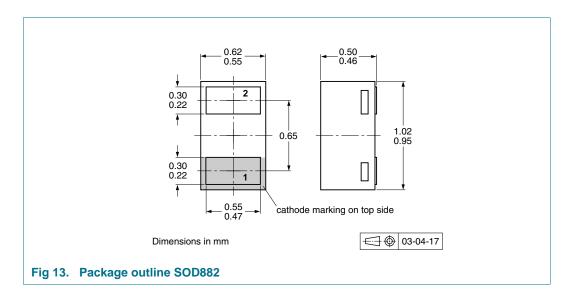
 $I_{RMS}=I_{F(AV)}$ at DC, and $I_{RMS}=I_{M}\times\sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 8. Packing methods

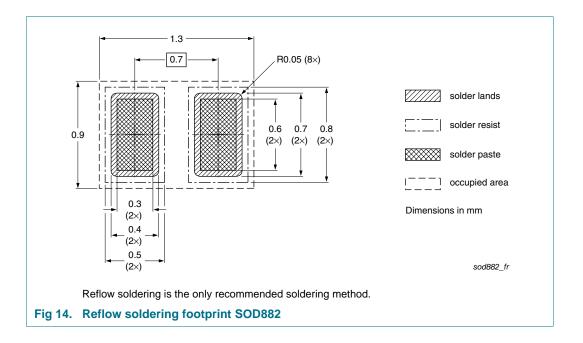
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity 10 000
RB520CS30L	SOD882	2 mm pitch, 8 mm tape and reel	-315

^[1] For further information and the availability of packing methods, see $\underline{\text{Section 14}}$.

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11. Soldering



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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
RB520CS30L v.1	20110310	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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